

OVERVIEW

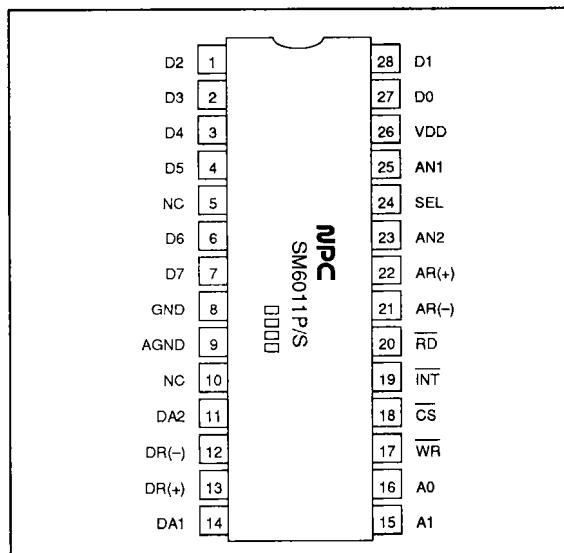
The SM6011 is a high-speed data converter fabricated in Molybdenum-gate CMOS. It comprises one 8-bit A/D converter, which uses a half-flash conversion method, and two 8-bit voltage-output D/A converters. The A/D converter does not require an external sample-and-hold circuit. Digital data can easily be interfaced with the data bus of common CPUs.

The SM6011 is available in 28-pin plastic DIPs and 28-pin SOPs.

FEATURES

- A/D converter
 - 8-bit resolution
 - 1.0 μ s (max) conversion time
 - Internal sample-and-hold circuits not required
 - Built-in 2-channel multiplexer
- D/A converter
 - 8-bit resolution
 - 2.5 μ s (max) settling time
 - Voltage output waveform
 - 2 channels
- Internal clock not required
- Low power consumption
- Can be connected directly to a CPU
- Single 5 V supply
- 28-pin plastic DIP and 28-pin SOP
- Molybdenum-gate CMOS process

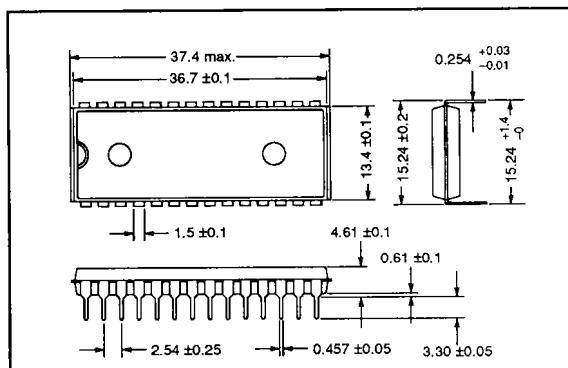
PINOUT



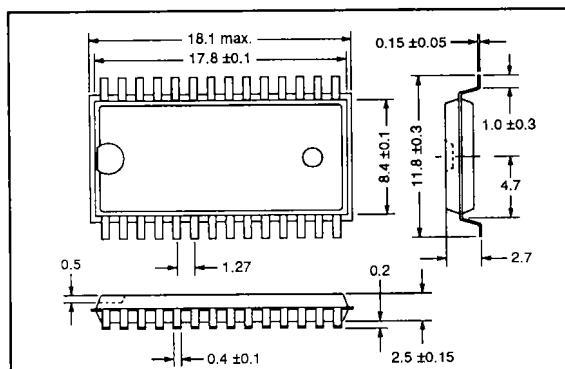
PACKAGE DIMENSIONS

Unit: mm

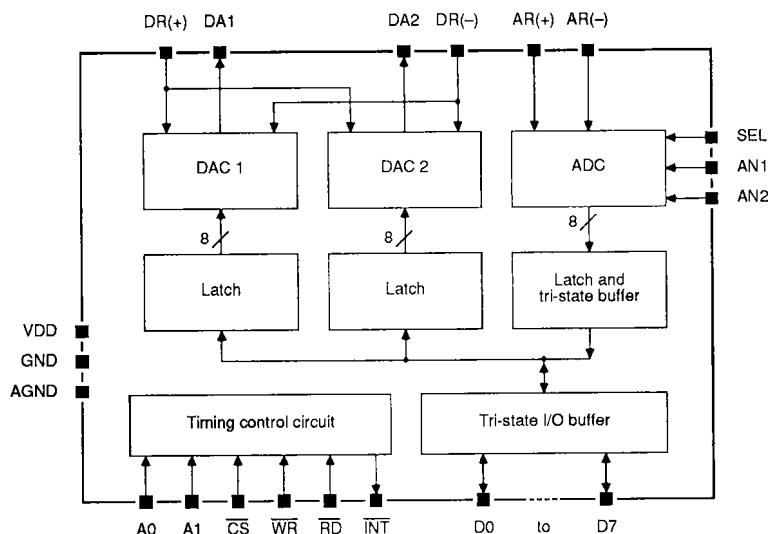
28-pin plastic DIP



28-pin SOP



BLOCK DIAGRAM



PIN DESCRIPTION

Number	Name	Description
1	D2	Parallel I/O port bit 2
2	D3	Parallel I/O port bit 3
3	D4	Parallel I/O port bit 4
4	D5	Parallel I/O port bit 5
5	NC	No connection
6	D6	Parallel I/O port bit 6
7	D7	Parallel I/O port bit 7 (MSB)
8	GND	Digital ground
9	AGND	Analog ground
10	NC	No connection

Number	Name	Description
11	DA2	D/A converter analog output 2
12	DR-	D/A converter reference voltage (low end voltage)
13	DR+	D/A converter reference voltage (high end voltage)
14	DA1	D/A converter analog output 1
15	A1	Function select pin 2
16	A0	Function select pin 1
17	WR	A/D converter start signal D/A converter write signal
18	CS	Chip select
19	INT	A/D converter interrupt output (conversion completed)
20	RD	A/D converter data read out
21	AR-	A/D converter reference voltage (low end voltage)
22	AR+	A/D converter reference voltage (high end voltage)
23	AN2	A/D converter channel 2 analog input
24	SEL	A/D converter analog channel input select (Ch. 1/Ch. 2)
25	AN1	A/D converter channel 1 analog input
26	VDD	Power supply
27	D0	Parallel I/O port bit 0 (LSB)
28	D1	Parallel I/O port bit 1

GENERAL SPECIFICATIONS

Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage range	V _{DD}	V _{GND} – 0.3 to 7.0	V
Input voltage range	V _{IN}	V _{GND} – 0.3 to V _{DD} + 0.3	V
Output voltage range	V _{OUT}	V _{GND} – 0.3 to V _{DD} + 0.3	V
Power dissipation	P _D	450	mW
Storage temperature range	T _{stg}	-40 to 125	deg. C
Soldering temperature	T _{sld}	260	deg. C
Soldering time	t _{sld}	10	s

Recommended Operating Conditions

Parameter	Symbol	Rating			Unit
		Min	Typ	Max	
Supply voltage	V _{DD}	4.75	5.0	5.25	V
Operating temperature	T _{opr}	-20	-	70	deg. C

Logic DC Electrical Characteristics $V_{DD} = 5 \text{ V} \pm 5\%$, $T_a = -20$ to 70 deg. C unless otherwise noted

Parameter	Symbol	Condition	Rating			Unit
			Min	Typ	Max	
D0 to D7, A0, A1, SEL, \overline{CS} , \overline{WR} and \overline{RD} HIGH-level input voltage	V_{IH}		3.5	-	-	V
D0 to D7, A0, A1, SEL, \overline{CS} , \overline{WR} and \overline{RD} LOW-level input voltage	V_{IL}		-	-	1.0	V
A0, A1, SEL, \overline{CS} , \overline{WR} and \overline{RD} HIGH-level input current	I_{IH1}	$V_{IH} = V_{DD}$	-	-	1	μA
D0 to D7 HIGH-level input current	I_{IH2}	$V_{IH} = V_{DD}$	-	-	3	μA
A0, A1, SEL, \overline{CS} , \overline{WR} and \overline{RD} LOW-level input current	I_{IL1}	$V_{IL} = V_{GND}$	-1	-	-	μA
D0 to D7 LOW-level input current	I_{IL2}	$V_{IL} = V_{GND}$	-3	-	-	μA
D0 to D7 and \overline{INT} HIGH-level output voltage	V_{OH}	$I_{OH} = -0.4 \text{ mA}$	3.5	-	-	V
D0 to D7 and \overline{INT} LOW-level output voltage	V_{OL}	$I_{OL} = 1.6 \text{ mA}$	-	-	0.4	V
Current consumption	I_{DD}		-	8	15	mA
Input pin capacitance	C_{IN}		-	5	-	pF
Output pin capacitance	C_{OUT}		-	5	-	pF

A/D CONVERTER SPECIFICATIONS**Conversion Characteristics** $V_{DD} = 5 \text{ V} \pm 5\%$, $V_{AR+} = 5 \text{ V} \pm 5\%$, $V_{AR-} = V_{GND}$, $T_a = -20$ to 70 deg. C

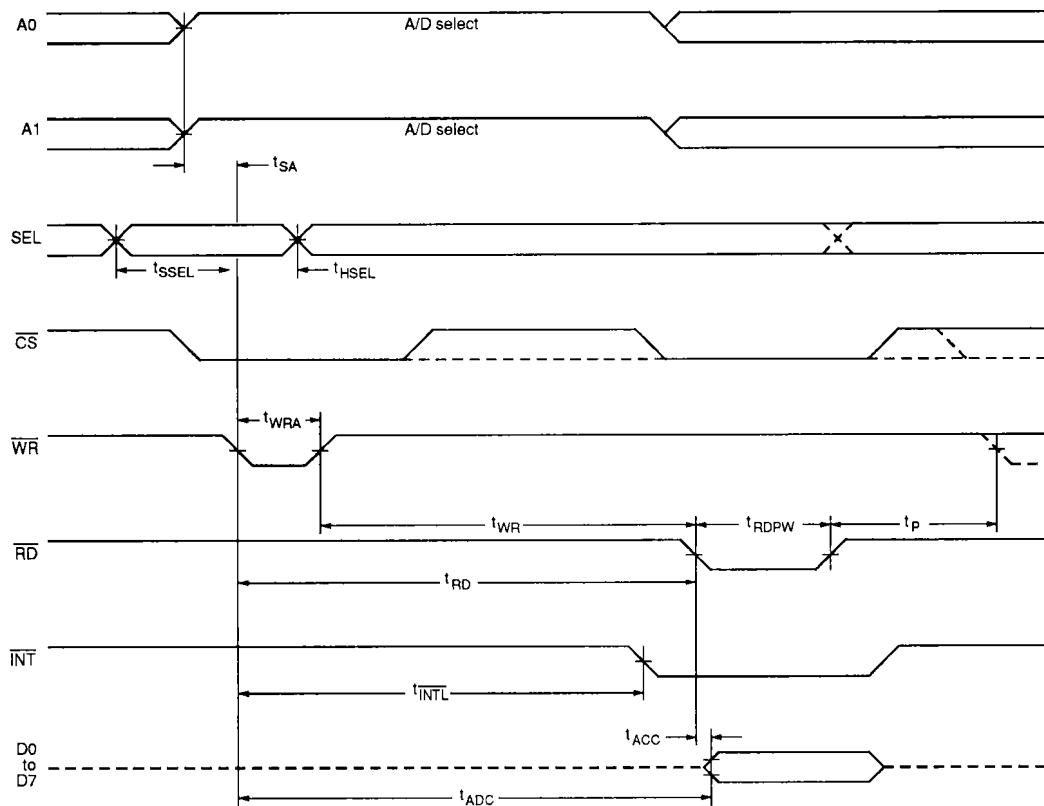
Parameter	Rating			Unit
	min	typ	max	
Resolution	8	-	-	bit
Non-linearity	-	-	± 0.7	LSB
Differential non-linearity	-	-	± 0.7	LSB
Offset error	0	1.0	2.0	LSB
Full-scale error	-	-	± 0.75	LSB

DC Electrical characteristics $V_{DD} = 5 \text{ V} \pm 5\%$, $T_a = -20$ to 70 deg. C

Parameter	Symbol	Condition	Rating			Unit
			min	typ	max	
AR+ to AR- reference resistance			0.5	0.85	1.3	kΩ
AR+ input voltage	V_{AR+}		V_{AR-}	-	$V_{DD} + 0.3$	V
AR- input voltage	V_{AR-}		V_{GND}	-	V_{AR+}	V
Analog input voltage			$V_{GND} - 0.1$	-	$V_{DD} + 0.1$	V
Analog input leakage current		$V_{IN} = V_{GND}$ to V_{DD} , $V_{CS} = V_{DD}$	-	± 0.1	± 3	μA
Analog input capacitance			-	25	-	pF

AC Electrical characteristics $V_{DD} = 5 \text{ V} \pm 5\%$, $T_a = -20$ to 70 deg. C

Parameter	Symbol	Condition	Rating			Unit
			min	typ	max	
Conversion time	t_{ADC}	$t_{RD} = 850 \text{ ns}$	-	-	1.0	μs
WR pulsewidth	t_{WRA}		200	-	700	ns
WR to RD setup time	t_{RD}		850	-	-	ns
Data access time	t_{ACC}	$R_L = 10 \text{ kΩ}$, $C_L = 15 \text{ pF}$	-	-	150	ns
WR to INT delay time	t_{INTL}		-	-	850	ns
RD pulsewidth	$t_{RD PW}$		150	-	-	ns
Input select setup time	t_{SEL}		500	-	-	ns
Input select hold time	t_{HSEL}		100	-	-	ns
Succeeding conversion wait time	t_p		500	-	-	ns
WR to RD pulse interval	t_{WR}		20	-	-	ns

A/D Converter to Data Read Out Timing**Note**

When converter data is to be transmitted to a D/A converter, A0 and A1 must be set after \overline{WR} goes HIGH and before \overline{RD} goes LOW.

D/A CONVERTER SPECIFICATIONS**Conversion Characteristics**

$V_{DD} = 5 \text{ V} \pm 5\%$, $V_{DR+} = 3 \text{ V}$, $V_{DR-} = 1.0 \text{ V}$, $T_a = -20 \text{ to } 70 \text{ deg. C}$

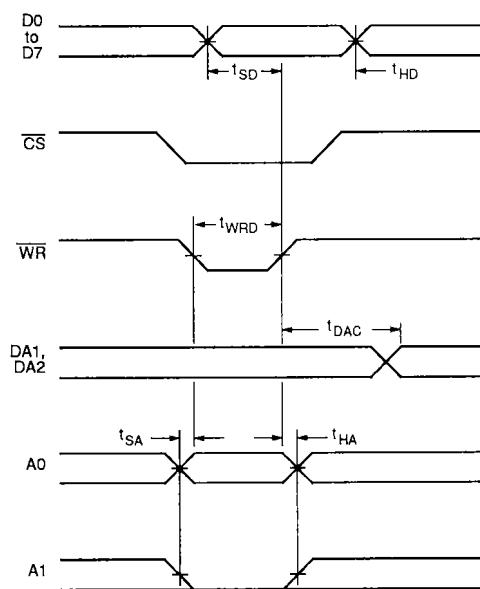
Parameter	Rating			Unit
	min	typ	max	
Resolution	8	-	-	bit
Non-linearity	-	-	± 1	LSB
Differential non-linearity	-	-	± 0.5	LSB
Offset error	-2.0	-0.5	1.0	LSB
Full-scale error	-2.5	-1.0	0.5	LSB

DC Electrical Characteristics $V_{DD} = 5 \text{ V} \pm 5\%$, $T_a = -20$ to 70 deg. C

Parameter	Symbol	Condition	Rating			Unit
			min	typ	max	
DR+ to DR- reference resistance			6	10	-	kΩ
DR+ input voltage	V_{DR+}		V_{DR-}	-	3.25	V
DR- input voltage	V_{DR-}		0.5		V_{DR+}	V
Output voltage range			V_{DR-}		$V_{DR+} - 1$ LSB	V
Load error		$R_L = 10 \text{ k}\Omega$	-	-	± 0.5	LSB

AC Electrical Characteristics $V_{DD} = 5 \text{ V} \pm 5\%$, $V_{DR+} = 3 \text{ V}$, $V_{DR-} = 1.0 \text{ V}$, $T_a = -20$ to 70 deg. C

Parameter	Symbol	Condition	Rating			Unit
			min	typ	max	
Settling time (full-scale transition)	t_{DAC}	$R_L = 10 \text{ k}\Omega$, $C_L = 15 \text{ pF}$	-	-	2.5	μs
Data setup time	t_{SD}		150	-	-	ns
Data hold time	t_{HD}		10	-	-	ns
WR pulsewidth	t_{WRD}		150	-	-	ns
Mode switching setup time	t_{SA}		20	-	-	ns
Mode switching hold time	t_{HA}		20	-	-	ns

D/A Converter Data Write Timing

FUNCTIONAL DESCRIPTION

The SM6011 comprises one 8-bit A/D half-flash converter and two 8-bit voltage-output D/A converters. The reference voltages for the A/D and D/A converters are generated independently.

The A/D converter analog input is a 2-channel multiplexed signal where the level on SEL determines which input is active.

The A/D converter output and D/A converter input is a common, parallel input/output bus (D0 to D7). The SM6011 can also transfer A/D converter output directly to either of the D/A converters at the same time as the output appears on the input/output bus. These functions are selected by control signals as shown in the following table.

Table 1. Function select

CS	RD	WR	A0	A1	Function
HIGH	×	×	×	×	No operation
×	HIGH	HIGH	×	×	No operation
LOW	HIGH	LOW	HIGH	HIGH	A/D converter start
LOW	LOW	HIGH	HIGH	HIGH	A/D converter read out
LOW	HIGH	LOW	LOW	LOW	DA1 data write
LOW	HIGH	LOW	HIGH	LOW	DA2 data write
LOW	LOW	HIGH	LOW	LOW	A/D converter data → DA1 write
LOW	LOW	HIGH	HIGH	LOW	A/D converter data → DA2 write

Note

× = don't care

Table 2. A/D Converter input channel select

SEL	Channel
LOW	AN1
HIGH	AN2

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